## Slotted Optical Switch



## Description:

The OPB847 and OPB848 consists of a gallium aluminum arsenide LED and a silicon phototransistor, which is soldered into a printed PCBoard and mounted in a high-temperature plastic housing on opposite sides of a 0.100 inch ( 2.540 mm ) wide slot. Both device types have a $.025(0.635 \mathrm{~mm})$ inch by .060 inch ( 1.524 mm ) aperture in front of the phototransistor for high resolution positioning sensing. Phototransistor switching takes place when an opaque object passes through the slot.

## Applications:

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety

| Part Number | LED Peak <br> Wavelength | Sensor | Slot Width / <br> Depth | Aperture <br> Emitter/Sensor | Lead Length / <br> Spacing |
| :--- | :---: | :---: | :---: | :---: | :---: |
| OPB847 | 890 nm | Transistor | $0.100 " / 0.250^{\prime \prime}$ | $0.025^{\prime \prime} / 0.025^{\prime \prime}$ | $0.425 / / 0.300 "$ |
| OPB848 |  |  |  |  |  |



| Pin \# | Description |
| :---: | :---: |
| 1 | Anode |
| 2 | Cathode |
| 3 | Emitter |
| 4 | Collector |




RoHS


## Electrical Specifications

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Operating and Storage Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Lead Soldering Temperature $[1 / 16$ inch $(1.6 \mathrm{~mm})$ from the case for 5 sec. with soldering iron] | $240^{\circ} \mathrm{C}$ |

## Input Diode

| Forward DC Current | 50 mA |
| :--- | :---: |
| Reverse Voltage | 2.0 V |
| Power Dissipation ${ }^{(2)}$ | 100 mW |

Output Phototransistor

| Collector-Emitter Voltage | 30 V |
| :--- | ---: |
| Emitter-Collector Voltage | 7 V |
| Power Dissipation $^{(2)}$ | 100 mW |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

Input Diode

| $V_{\text {F }}$ | Forward Voltage ${ }^{(4)}$ | 1.00 | 1.35 | 1.70 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | 1.20 | 1.55 | 1.90 |  | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=-55^{\circ} \mathrm{C}$ |
|  |  | 1.80 | 1.20 | 1.60 |  | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | - | 0.10 | 100 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{R}}=2 \mathrm{~V}$ |

## Output Phototransistor

| $\mathrm{V}_{(\mathrm{BR}) \text { CEO }}$ | Collector-Emitter Breakdown Voltage | 30 | 110 | - | V | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{~V}_{\text {(BR)ECO }}$ | Emitter-Collector Breakdown Voltage | 5 | 10 | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0$ |
| $\mathrm{I}_{\mathrm{CEO}}$ | Collector-Emitter Dark Current | - | 0.20 | 100 | nA | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0$ |
|  |  | - | 10 | 100 | $\mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C}$ |

Notes:
(1) Duration can be extended to 10 seconds maximum when flow soldering.
(2) Derate linearly $1.00 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(3) Methanol and isopropanol are recommended as cleaning agents.
(4) Measurement is taken during the last $500 \mu$ s of a single 1.0 ms test pulse. Heating due to increased pulse rate or pulse width can cause change in measurement results.

## Slotted Optical Switch

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Combined

| $\mathrm{I}_{\text {(ON) }}$ | On-State Collector Current ${ }^{(1)}$ OPB847 <br> OPB848 | $\begin{aligned} & 4.0 \\ & 1.0 \end{aligned}$ |  |  | mA | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CE(SAT) }}$ | ```Collector-Emitter Saturation Voltage OPB847 OPB848``` |  | $\begin{aligned} & 0.30 \\ & 0.30 \end{aligned}$ | $\begin{aligned} & 0.40 \\ & 0.40 \end{aligned}$ | V | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=500 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time OPB847 <br> OPB848 |  | $\begin{gathered} 12 \\ 8 \end{gathered}$ | $\begin{aligned} & 20 \\ & 15 \end{aligned}$ | $\mu \mathrm{s}$ | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=1000 \Omega$ |
| $\mathrm{t}_{\mathrm{f}}$ | Output Fall Time OPB847 OPB848 |  | 12 8 | $\begin{aligned} & 20 \\ & 15 \end{aligned}$ |  |  |

(1) Measurement is taken during the last $500 \mu$ s of a single 1.0 ms test pulse. Heating due to increased pulse rate or pulse width can cause change in measurement results.


PPB847 - Flag in Middle of Slot



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